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AMENDMENTS TO THE SPECIFICATION

Please amend the specification as follows. A clean version and marked-up version is provided:

Clean version:

- At page 1, before line 1, delete title and insert:

CIRCUIT ARRANGEMENT WITH NON-VOLATILE MEMORY MODULE AND METHOD FOR EN-/DECRYPTING DATA IN THE NON-VOLATILE MEMORY MODULE

BACKGROUND OF THE INVENTION

- At page 1, line 10 delete the paragraph in full and replace it with:
- having at least one code Read Only Memory (ROM) module for storing at lease one ROM code; and
- At page 1, lines 18 through 26, delete both paragraphs in full and replace with:

DESCRIPTION OF RELATED ART

Conventionally, key codes necessary for encrypting or decrypting the contents of a Non-Volatile (NV) memory module are either hard-coded, defined by means of fuse cells especially instantiated therefore or saved themselves in a specially protected area of the non-volatile memory module.

Each of these known procedures has disadvantages, however: in the case of hardcoded keys, the key code cannot be changed for different controller versions with different ROM codes; in the case of the more flexible definition of the key code in fuse cells or in the

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case of protected Electrical Erasable Programmable Read Only Memory (EEPROM) areas, the key length is limited as a result of cell or surface area requirements.

SUMMARY OF THE INVENTION

- At page 2, lines 4 through 11, delete both paragraphs in full and replace with:

This object is achieved with a circuit arrangement having the features indicated in Figure 1 and by an en-/decryption method based thereon having the features discussed herein below. Advantageous embodiments and expedient further developments of the present invention are identified herein as well.

According to the teaching of the present invention, therefore, a completely new approach is disclosed to the generation of at least one especially long key for the endecryption of at least one NV memory module from ROM code data, for example for embedded security controllers.

- At page 2, line 32 through page 3, line 2, delete the paragraph in full and replace it with:

Through double use of the ROM code as a source for long key codes, the security of the encryption or decryption of the NV memory module is increased by greater key lengths, without such a greater key length resulting in a corresponding additional surface area requirement for storing this key code,

- At page 3, lines 15 through 33, delete all paragraphs in full and replace with:

BRIEF DESCRIPTION OF THE DRAWINGS

As already discussed above, there are various possible ways of advantageously embodying and developing the teaching of the present invention. The invention will be further described with reference to examples of embodiments shown in the drawings to which, however, the invention is not restricted. In the Figures:

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Fig. 1 is a schematic block diagram of an example of an embodiment of a circuit arrangement according to the present invention, by means of which the en-/decryption method may be performed according to the present invention.

DETAILED DESCRIPTION OF THE EXEMPLARY EMBODIMENTS OF THE INVENTION

Fig. 1 shows an example of an embodiment of a circuit arrangement 100 for electronic data processing; in particular, the circuit arrangement 100 is provided for use in a microcontroller of the "embedded security controller" type.

This circuit arrangement 100 comprises a multi-component NV memory module 10; which takes the form of an EEPROM and by means of which data may be stored which are to be protected from unauthorized access by encryption or decryption.

Assigned to this NV memory module 10 is a memory module interface logic circuit 12, by means of which

- At page 4, lines 10 through 13, delete the paragraph in full and replace it with:

In addition, the circuit arrangement 100 comprises a code ROM module 20 for storing and supplying ROM codes. Assigned to this code ROM module 20 is code ROM module interface logic circuit 22 by means of which

At page 4, lines 23 through 30, delete the paragraph in full and replace it with:

To this end, the memory module interface logic circuit 12 comprises an en-/decryption logic circuit 14 having a key address generation unit 16 and a key register 18. The key address generation unit 16 is provided in this context for the purpose of generating an ROM key address (-) reference numeral 162a: ROM key address data from the key address generation unit 16 to a multiplexing unit 24 of the code ROM module interface logic circuit 22) in the case of write or read access to the memory module 10 using a memory module address coming from the Central Processing Unit (CPU) (→ reference numeral C12a: address data "CPU NV addr" from the CPU to the memory module interface logic circuit 12).

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- At page 6, lines 10 through 18, delete both paragraphs and replace with:

For encryption (in the event of write access, reference numeral 120w) or decryption (in the event of read access, reference numeral 120r) of the NV memory data "DIN(d:0)" or "DOUT(d:0)", this ROM code byte is then used as a key byte or as part of the key byte, such that in an extreme case a key space is produced which is of exactly the same size as the code space of the NV memory module 10.

(ii) Generation of the key code in the reset phase, i.e. by one of reading out of particular ROM code bytes, in particular at the time of the reset sequence, and by storing these ROM code bytes in the key register 18 until the time of a write/read access to the memory module 10, i.e. until these ROM code bytes are required for a write operation or a read operation of the memory module 10:

- At page 7, line 2, delete the entire line and replace it with:

10 NV memory module

- At page 7, line 8, delete the entire line and replace it with:

20 Code ROM module

- Please delete the Abstract in its totality and replace it with:

An apparatus and method is provided for protecting data in a non-volatile memory by using an encryption and decryption that encrypts and decrypts the address and the data stored in the non-volatile memory using a code read only memory that stores encryption and decryption keys that are addressed by a related central processing unit at the same time data is being written or read from the non-volatile memory by the central processing unit.

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Marked-up version:

- At page 1, before line 1, delete the title and insert:

Circuit arrangement with non-volatile memory module and method for en /decrypting data in the non-volatile memory module

CIRCUIT ARRANGEMENT WITH NON-VOLATILE MEMORY MODULE AND
METHOD FOR EN-/DECRYPTING DATA IN THE NON-VOLATILE MEMORY
MODULE

BACKGROUND OF THE INVENTION

- At page 1, line 10, delete the paragraph in full and replace it with:
- having at least one code R[ead]O[nly]M[emory] Read Only Memory (ROM)
 module for storing at lease one R[ead]O[nly]M[emory] ROM code; and
- At page 1, lines 18 through 26, delete both paragraphs in full and replace with:

DESCRIPTION OF RELATED ART

Conventionally, key codes necessary for encrypting or decrypting the contents of a NionjV[olatile]Non-Volatile (NV) memory module are either hard-coded, defined by means of fuse cells especially instantiated therefore or saved themselves in a specially protected area of the non-volatile memory module.

Each of these known procedures has disadvantages, however: in the case of hard-coded keys, the key code cannot be changed for different controller versions with different ROM codes; in the case of the more flexible definition of the key code in fuse cells or in the case of protected E[lectrical] E[rasable] P[regrammable] R[cad] O[nly] M[emory] Electrical Erasable Programmable Read Only Memory (EEPROM) areas, the key length is limited as a result of cell or surface area requirements.

SUMMARY OF THE INVENTION

SENT BY: HOWISON, & ARNO;

Docket No.: DE02 0274 US

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At page 2, lines 4 through 11, delete both paragraphs in full and replace with:

This object is achieved with a circuit arrangement having the features indicated in elaim 1 Figure 1 and by an en-/decryption method based thereon having the features discussed herein below indicated in elaim 6. Advantageous embodiments and expedient further developments of the present invention are identified herein as well. in the respective dependent claims.

According to the teaching of the present invention, therefore, a completely new approach is disclosed to the generation of at least one especially long key for the endecryption of at least one Non-Volatile NV memory module from Read-Only Memory ROM code data, for example for embedded security controllers.

- At page 2, line 32 through page 3, line 2, delete the paragraph in full and replace it with:

Through double use of the ROM code as a source for long key codes, the security of the encryption or decryption of the N[en]V[olatile] NV memory module is increased by greater key lengths, without such a greater key length resulting in a corresponding additional surface area requirement for storing this key code.

- At page 3, lines 15 through 33, delete all paragraphs in full and replace with:

BRIEF DESCRIPTION OF THE DRAWINGS

As already discussed above, there are various possible ways of advantageously embodying and developing the teaching of the present invention. Reference is made, in this regard, to the claims subordinate to claims 1 and 6, and the The invention will be further described with reference to examples of embodiments shown in the drawings to which, however, the invention is not restricted. In the Figures:

Fig. 1 is a schematic block diagram of an example of <u>an</u> embodiment of a circuit arrangement according to the present invention, by means of which the en-/decryption method may be performed according to the present invention.

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INVENTION

Fig. 1 shows an example of an embodiment of a circuit arrangement 100 for electronic data processing; in particular, the circuit arrangement 100 is provided for use in a microcontroller of the "embedded security controller" type.

This circuit arrangement 100 comprises a multi-component N[en]V[olatile] NV memory module 10, which takes the form of an Effectiveal Efrasoble! Pirogrammable R[end] O[nly] M[emory] EEPROM and by means of which data may be stored which are to be protected from unauthorized access by encryption or decryption.

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In addition, the circuit arrangement 100 comprises a code R[ead] O[nly] M[emery] ROM module 20 for storing and supplying Read Ofnly Memory ROM codes. Assigned to this code ROM module 20 is code ROM module interface logic circuit 22 by means of which .

- At page 4, lines 23 through 30, delete the paragraph in full and replace it with:

To this end, the memory module interface logic circuit 12 comprises an en-/decryption logic circuit 14 having a key address generation unit 16 and a key register 18. The key address generation unit 16 is provided in this context for the purpose of generating an ROM key address (> reference numeral 162a: ROM key address data from the key address generation unit 16 to a multiplexing unit 24 of the code ROM module interface logic circuit 22) in the case of write or read access to the memory module 10 using a memory module address coming from the Cfentral Pfreeessing Ufnit Central Processing Unit (CPU) (→ reference numeral C12a: address data "CPU NV addr" from the CPU to the memory module interface logic circuit 12).

At page 6, lines 10 through 18, delete both paragraphs and replace with:

For encryption (in the event of write access, reference numeral 120w) or decryption (in the event of read access, reference numeral 120r) of the NV memory data "DIN(d:0)" or "DOUT(d:0)", this ROM code byte is then used as a key byte or as part of the key byte, such that in an extreme case a key space is produced which is of exactly the same size as the code space of the Non Volatile NV memory module 10.

- (ii) Generation of the key code in the reset phase, i.e. by one off one of reading out of particular ROM code bytes, in particular at the time of the reset sequence, and by storing these ROM code bytes in the key register 18 until the time of a write/read access to the memory module 10, i.e. until these ROM code bytes are required for a write operation or a read operation of the memory module 10:
- At page 7, line 2, delete the entire line and replace it with:
 - N[on]V[olatile] NV memory module
- At page 7, line 8, delete the entire line and replace it with:
 - Code R[end] O[nly] M[emory] ROM module
- Please delete the Abstract in its totality and replace it with:

An apparatus and method is provided for protecting data in a non-volatile memory by using an encryption and decryption that encrypts and decrypts the address and the data stored in the non-volatile memory using a code read only memory that stores encryption and decryption keys that are addressed by a related central processing unit at the same time data is being written or read from the non-volatile memory by the central processing unit.

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